

Features

- Frequency Range: DC~12GHz
- Isolation: >42dB@12GHz
- Insertion loss: 1.4dB@12GHz
- Control Voltage: 0/+5V
- Package Size: 3mm×3mm×1.2mm

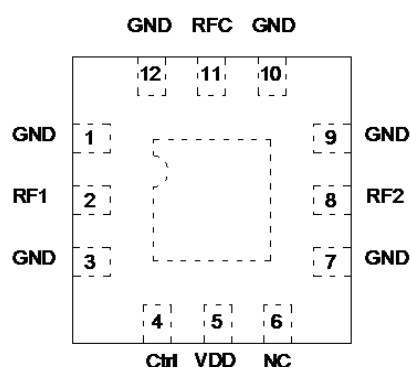
Typical Applications

- Radar and ECM
- RF/ Microwave radio
- Military and Space
- Test and Measurement
- Fiber Optics

General Description

XT3202Q3 is a general purpose broadband high isolation reflective GaAs pHEMT SPDT switch in bare die. The switch offers over 42 dB isolation and less than 1.4dB insertion loss over operation frequency. Its fast switching and compact size make this SPDT ideal for a lot of critical applications. The switch operates using complementary positive control voltage logic lines of 0/+5V.

Functional Diagram



Electrical Performance

($T_A = +25^{\circ}\text{C}$, $V_{DD} = -5\text{V}$, Control Voltage = 0/+5V, $Z_0 = 50\Omega$)

Parameter	Freq.	Min.	Typ.	Max.	Units
Insertion Loss	DC~12GHz	—	-1.1	-1.4	dB
Isolation	DC~12GHz	-42	-48	—	dB
Return Loss(RFC)	DC~12GHz	-15	-20	—	dB
Return Loss(RF1,RF2)	DC~12GHz	-15	-20	—	dB
Input $P_{1\text{dB}}$	DC~12GHz	—	25	—	dBm
Input IP_3	DC~12GHz	—	42	—	dBm
Switching Speed	DC~12GHz	—	18	—	ns

Absolute Maximum Ratings

Input power	30dBm	Control Voltage Range	0~5.5V
Channel Temperature	150°C	Storage Temperature	-65°C~+150°C
Operating Temperature	-55°C~+85°C	ESD Sensitivity (HBM)	Class 1A

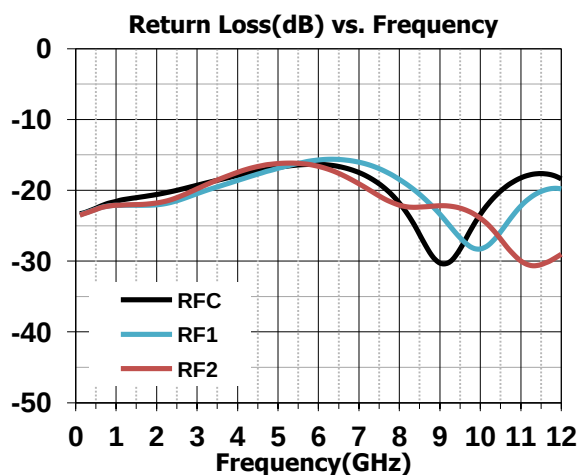
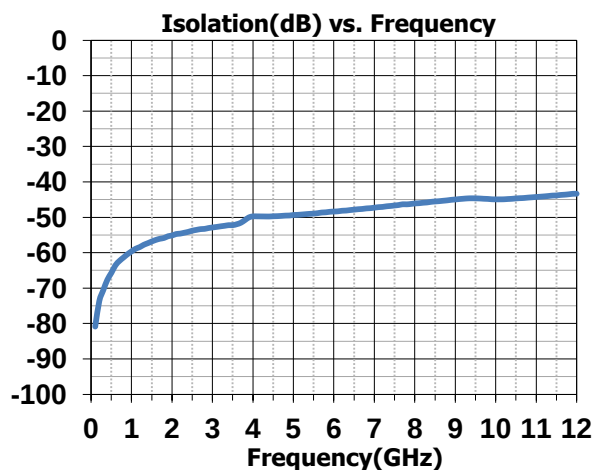
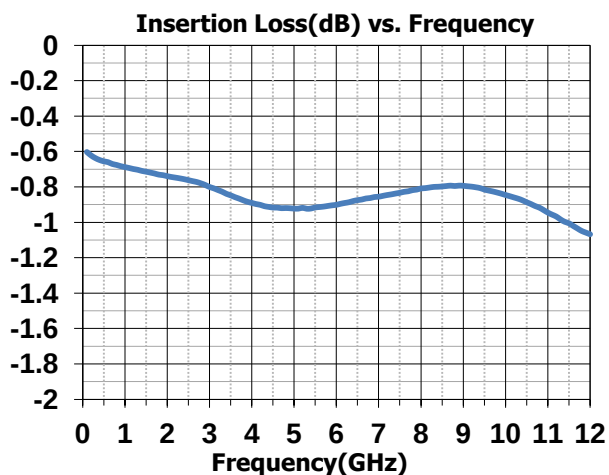
XT3202Q3



GaAs MMIC SPDT Switch
DC~12GHz

Rev 1.1

Typical Performance Curve



Control Voltages

State	Bias Condition
Low	0~ 0.5V
High	4.5~ 5.5V

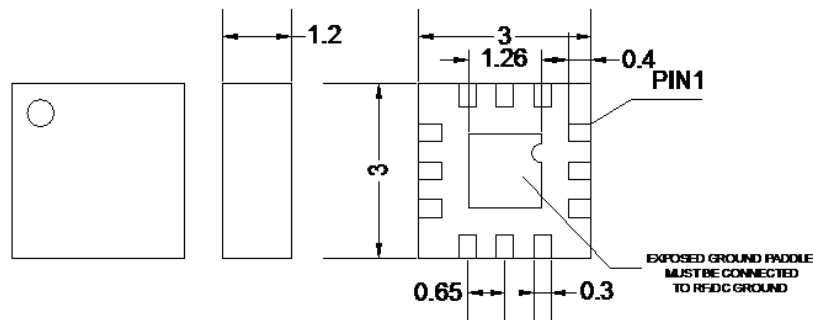
Truth Table

Control Input	Signal Path State	
Control	RFC-RF1	RFC-RF2
Low	ON	OFF
High	OFF	ON

Bias Voltage & Current

V _{DD}	I _{DD}
-5V	1mA

Outline Drawing (all dimensions in mm)



Attention:

1. The moisture resistant grade of products is 2A, the storage environment $\leq 30^{\circ}\text{C}/60\%\text{RH}$, The surrounding workshop Life is 4 weeks.
2. After un-packing, It is necessary to bake the parts for 6 hours in 125 ± 5 degree environment before soldering.